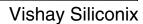
COMPLIANT

FREE Available





N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
20	$0.0027 \text{ at V}_{GS} = 4.5 \text{ V}$	25		
	0.0042 at V _{GS} = 2.5 V	22		

SO-8 S 1 8 D S 2 7 D S 3 6 D Top View

Ordering Information: Si4378DY-T1-E3 (Lead (Pb)-free)

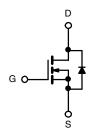
Si4378DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- Ultra Low On-Resistance Using High Density TrenchFET[®] Gen II Power MOSFET Technology
- Q_g Optimized
- 100 % R_g Tested

APPLICATIONS

- · Synchronous Rectification
- Point-Of-Load



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	s otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20		V
Gate-Source Voltage		V_{GS}	± 12		V
Continuous Dunin Courset /T 450 90\8	T _A = 25 °C	I _D 25 20	19	1	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		20	13	Í
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	70		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3	
Avalanche Current	L = 0.1 mH	I _{AS}	40		
Mariana Barra Biratina	T _A = 25 °C	D_	3.5	1.6	W
Maximum Power Dissipation ^a	T _A = 70 °C	- P _D	2.2	1	l vv
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 s	R _{thJA}	29	35		
Maximum Junction-to-Ambient ^a	Steady State	□thJA	67	80	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16		

Notes

a. Surface Mounted on 1" x 1" FR4 board.

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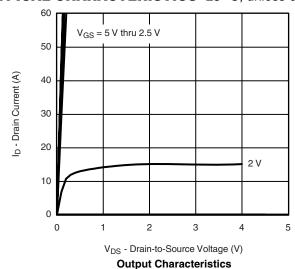
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		1.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvain Curvent	1	V _{DS} = 20 V, V _{GS} = 0 V			1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V, T _J = 55 °C			5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			Α	
	В	$V_{GS} = 4.5 \text{ V}, I_D = 25 \text{ A}$		0.0022	0.0027	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 22 \text{ A}$		0.0034	0.0042		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 25 A		150		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.72	1.1	V	
Dynamic ^b							
Input Capacitance	C _{iss}			8500			
Output Capacitance	C _{oss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		1250		pF	
Reverse Transfer Capacitance	C _{rss}			650			
Total Gate Charge	Q_g			55			
Gate-Source Charge	Q _{gs}	V _{DS} = 10 V, V _{GS} = 4.5 V, I _D = 25 A		16		nC	
Gate-Drain Charge	Q_{gd}			10			
Gate Resistance	R_g		0.8	1.3	2.0	Ω	
Turn-On Delay Time	t _{d(on)}			85	130		
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		65	100		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A, } V_{GEN} = 4.5 \text{ V, } R_g = 6 \Omega$		140	210	ns	
Fall Time	t _f			50	80	1	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		50	80		

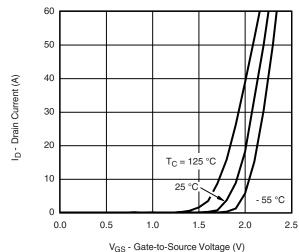
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



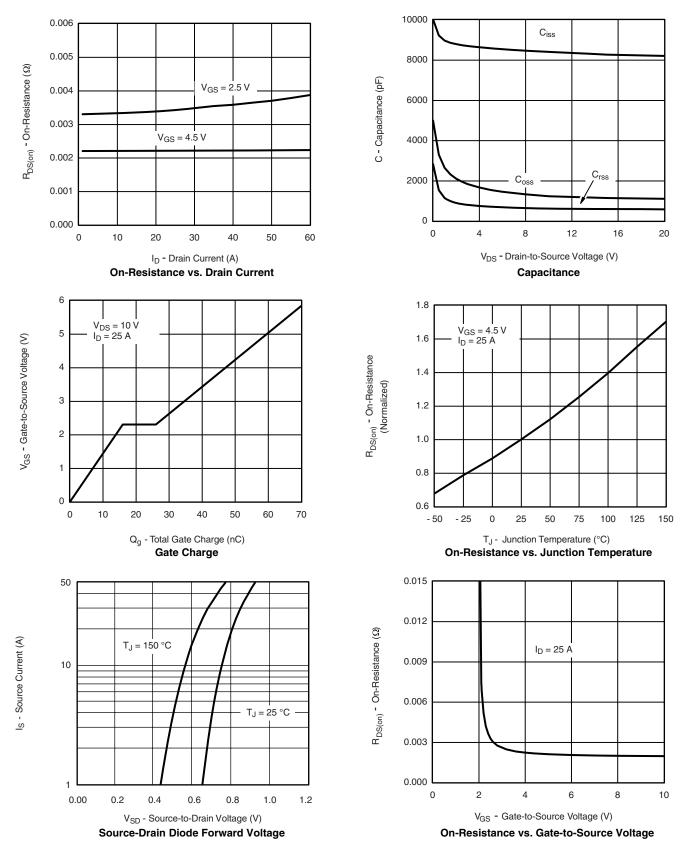








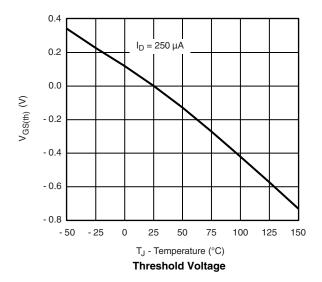
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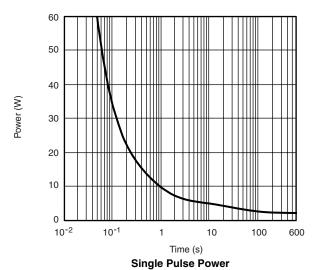


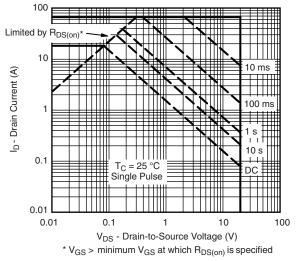
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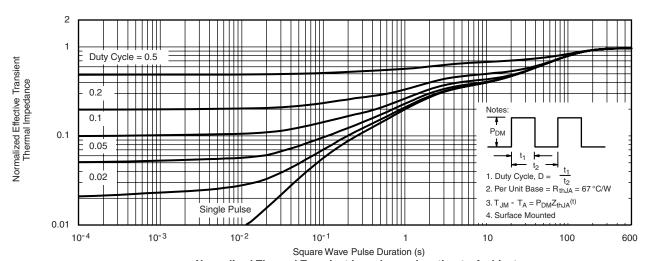
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





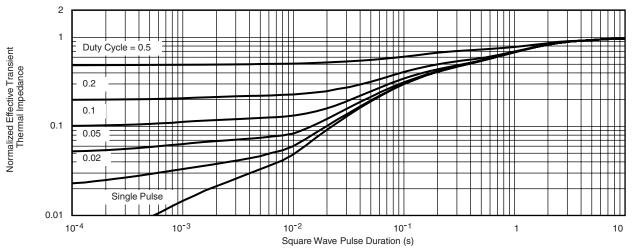


Safe Operating Area, Junction-to-Case





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72918.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES		
DIM	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
Е	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I. 11-Sep-06					

DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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